

# Product data sheet

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#### Specification Features:

- Stand-off Voltage: 5V0
- Low Leakage
- Response Time is Typically < 1ns</p>
- IEC61000-4-2 Level 4 ESD Protection
- RoHS Compliant
- Threen EMC
- Matte Tin(Sn) Lead Finish

SOD-523

#### Absolute Maximum Ratings T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
Vpp	IEC61000-4-2(ESD) Air Contact	土15 土8	KV
ESD	Per Human Body Model	16	KV
PD	Power Dissipation (Note 1)	150	mW
T <sub>STG</sub>	Storage Temperature Range	-55 to +150	°C
TJ	Operating Junction Temperature	+150	°C
ΤL	Max Lead Solder Temperature range(10 Second Duration)	260	°C

These ratings are limiting values above which the serviceability of the diode may be impaired. Note 1. FR-5 =  $1.0 \times 0.75 \times 0.62$  in.

#### Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

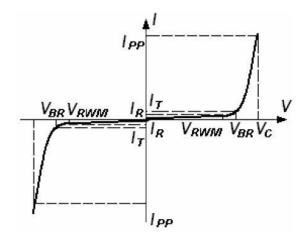
P/N	V <sub>RWM</sub> (Volts)	<b>Ι<sub>R</sub>@ V<sub>RWN</sub></b> (μΑ)	(No	@ I <sub>T</sub> te 2) blts)	I <sub>т</sub> (mA)	<b>І</b> <sub>РР+</sub> (А)	V <sub>c</sub> @ Max I <sub>PP+</sub> (Volts)	<b>Р</b> <sub>РК+</sub> (W)	C @ <b>V</b> <sub>R</sub> = 0V, f = 1MHz (pF)
	Мах	Мах	Min	Мах		Max	Мах	Мах	Тур.
PESD5V0S1BB-MS	5.0	1	5.6	7.8	1.0	4	12	48	15

+ Surge current waveform per Figure 1.

Note 2:  $V_{BR}$  is measured with a pulse test current  $I_{T}$  at an ambient temperature of 25°C.

### **Electrical Parameter**

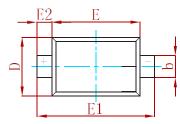
Symbol	Parameter		
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current		
$V_{\text{C}}$	Clamping Voltage @ I <sub>PP</sub>		
V <sub>RWM</sub>	Working Peak Reverse Voltage		
I <sub>R</sub> Maximum Reverse Leakage Curr			
Ι <sub>Τ</sub>	Test Current		
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>		

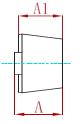


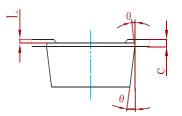


PESD5V0S1BB-MS Semiconductor

## PACKAGE MECHANICAL DATA

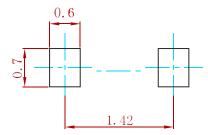






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	0.510	0.770	0.020	0.031	
A1	0.500	0.700	0.020	0.028	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	0.750	0.850	0.030	0.033	
E	1.100	1.300	0.043	0.051	
E1	1.500	1.700	0.059	0.067	
E2	0.200 REF		0.008 REF		
L	0.010	0.070	0.001	0.003	
0	7° REF		7° REF		

# Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.

3. The pad layout is for reference purposes only.

## **REEL SPECIFICATION**

P/N	PKG	QTY
PESD5V0S1BB-MS	SOD-523	3000



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